

Bose-Einstein Condensate in a light-induced vector gauge potential using the 1064 nm optical dipole trap lasers

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Using two crossed 1064 nm optical dipole trap lasers to be the Raman beams, an effective vector gauge potential for Bose-Einstein condensed ^{87}Rb in the $F = 2$ hyperfine ground state is experimentally created. The moderate strength of the Raman coupling still can be achieved when the detuning from atomic resonance is larger than the excited-state fine structure, since rubidium has 15 nm energy-level splitting. The atoms at the far detuning of the Raman coupling are loaded adiabatically into the dressed states by ramping the homogeneous bias magnetic field with different paths and the dressed states with different energies are studied experimentally. The experimental scheme can be easily extended to produce the synthetic magnetic or electric field by means of a spatial or time dependence of the effective vector potential.

Quantum degenerate gases in ultracold temperature offer us new opportunities to efficiently simulate quantum condensed matter systems [1]. It is an important advantage for experiments that the physical parameters of atomic systems, including the number of the trapped atoms, the shape of the trapping potential, and the strength of the atom-atom interaction can be precisely controlled. A fascinating example of utilizing atomic systems is that the vector potential of the charged particles in a magnetic field can be simulated by the ultracold atomic gas if a gauge field is applied on it. In this case, the strongly correlated states of matter, such as the fractional quantum Hall effect exhibited by electrons in a magnetic field, can be easily studied. A well-known method is to rotate the gas [2, 3], where the transformation to the rotating frame corresponds to giving the particles a fictitious charge, and applying an effective uniform magnetic field. Another approach is to induce gauge potentials through the laser-atom interactions [4, 5]. There are already various theoretical proposals for generating artificial abelian and non-abelian gauge fields without [6–10] or with optical lattices [11–17], and some exotic properties are predicted [6–21]. The experiment on the generation of synthetic gauge fields has had made great progress recently in the NIST group [22–25]. In Lin et al. experiment [22], the effective vector potential is generated by coupling a pair of 804.3 nm Raman laser beams into the magnetic sublevels of the $F = 1$ hyperfine level of the electronic ground state in a 1550 nm optically trapped Bose-Einstein condensate (BEC) of ^{87}Rb atoms. Successively, the synthetic magnetic [23] and electric fields [24] were also produced from a spatial variation and time dependence of the effective vector potential. Very recently, using the similar scheme BEC with spin-orbit coupling [25] has also been realized by the same group.

In this letter, we report a novel experimental scheme of generating light-induced vector gauge potential, in which the two 1064 nm optical dipole trap lasers are also used as a pair of Raman lasers in ^{87}Rb BEC. At first an opti-

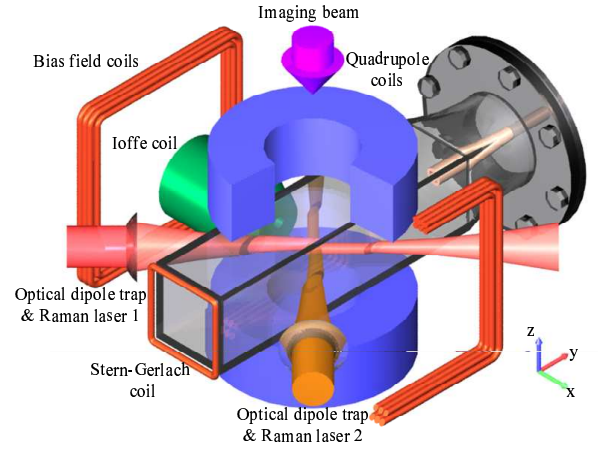


FIG. 1: (Color online). Schematic drawing of the experimental setup.

cally trapped BEC is created by the two crossed optical dipole trap lasers. Simultaneously, the two dipole trap lasers with a frequency difference resonant with the energy difference between the magnetic sublevels, couple these two magnetic sublevels of the $F = 2$ hyperfine level of the electronic ground state. We adiabatically load the atoms at the far detuning of the Raman coupling into the dressed state by ramping the bias magnetic field to resonance. The different energy dressed states are loaded and studied. The collision decay of the high energy dressed state is observed. The light-induced vector gauge potential by four-photon Raman process with $4\hbar k_R$ momentum is also observed. Our experimental setup can be easily extended to present the spatial or time dependent vector potential for producing synthetic magnetic or electric field.

The model with two-level system in Ref. [10, 25] is employed in the experiment [26]. We choose the two magnetic sublevels $|\uparrow\rangle = |F = 2, m_F = 2\rangle$ and $|\downarrow\rangle = |F = 2, m_F = 1\rangle$ of the $F = 2$ hyperfine level of the electronic ground state to be the two internal spin states, which

are coupled by a pair of Raman beams with strength Ω . In our experiment, the optical dipole trap is composed of two horizontal crossed beams at 90° along $\hat{x} \pm \hat{y}$ and overlapped at the focus, which also are used as two Raman beams, as shown in Fig. 1. The linear polarization of both beams is horizontal in the plane of x - y . Both beams are extracted from a 15 W laser (MOPA 15 NE, InnoLight Technology, Ltd.) operating at the wavelength of 1064 nm with the narrow linewidth single-frequency. Two beams single-pass through two acousto-optic modulators (AOM) (3110-197, Crystal Technology, Inc.). The Raman beam 1 and 2 are frequency shifted -100 MHz and -110.4 MHz by two signal generators (N9310A, Agilent) respectively. The frequency difference $\nu_R/2\pi = 10.4$ MHz of two signal generators are phase-locked by a source locking CW microwave frequency counters (EIP 575B, Phase Matrix Inc.). Thus two laser beams are phase-locked and frequency shifted 10.4 MHz relative to each other to avoid any spatial interference between the two beams, and at the same time provide the radio-frequency Raman coupling between two magnetic sublevels. Then two beams are coupled into two high power polarization maintaining single-mode fibers in order to increase stability of the beam pointing and obtain better beam-profile quality. Behind the fibers, one beam is focused to a waist size of $1/e^2$ radii of $38 \mu\text{m}$ by an achromatic lens of focus length $f = 300 \text{ mm}$, and the other beam is focused to $49 \mu\text{m}$ by a $f = 400 \text{ mm}$ lens. For enhancing the intensity stability of the two beams, a small fraction of the light is sent into a photodiode and the regulator is used for comparing the intensity measured by the photodiode to a set voltage value from the computer. The non-zero error signal is compensated by adjusting the radio power in the AOM in front of the optical fiber.

A homogeneous bias magnetic field provided by a pair of Helmholtz coils along \hat{y} gives a linear Zeeman shift $\omega_Z/2\pi$ between two magnetic sublevels, as shown in Fig. 1. To control the magnetic field precisely and reduce the magnetic field noise, the power supply (Delta SM70-45D) has been operated in remote voltage programming mode, whose voltage is set by an analog output of the experiment control system. The current through the coils is controlled by the external regulator relying on a precision current transducer (Danfysik ulastable 867-60I). The output error signal from the regulator actively stabilize the current with the PID (proportional-integral-derivative) controller acting on the MOSFET (metal-oxide-semiconductor field-effect transistor). In order to reduce the current noise and decouple the control circuit from the main current, a conventional battery is used to power the circuit.

In our experiment, ^{87}Rb atoms are first precooled to $1.5 \mu\text{K}$ by radio-frequency evaporative cooling in a quadrupole-Ioffe configuration (QUIC) trap [27, 28]. Subsequently, the atom sample is transferred back to the center of the glass cell [29] in favor of the opti-

cal access. After loading ^{87}Rb atoms in hyperfine state $|F = 2, m_F = 2\rangle$ into the dipole trap with the full powers (900 mW and 1.3 W) at a weak homogeneous bias magnetic field about 1 G, the forced evaporative cooling is performed by lowering the powers of two beams [30]. With the evaporation time of 1.2 s, the pure BEC with the atomic number of 2×10^5 is obtained at the powers of 169 mW (beam 1) and 320 mW (beam 2). In order to increase the Raman coupling strength, the powers of two dipole trap beams are increased to 207 mW (beam 1) and 480 mW (beam 2), respectively. The pure BEC is still maintained in the dipole trap with trap frequency of $2\pi \times 83 \text{ Hz}$ along \hat{x} and \hat{y} . Now we first measure the resonant Raman Rabi frequency Ω by observing population oscillations driven by the variable Raman pulse length. The third dipole trap beam (beam 3) with frequency shifted -103 MHz counterpropagating with the Raman beam 2 is utilized in the measurement process. The BEC is loaded adiabatically into the crossed dipole trap composed of Raman beam 1 and dipole trap beam 3 by ramping the dipole trap beam 3 and decreasing the intensity of the Raman beam 2 to zero. Then the homogeneous bias magnetic field is ramped to the value with $\hbar\delta = -4E_R$, so the atoms are resonant for $|\uparrow', 0\rangle \rightarrow |\downarrow', -2k_R\rangle$ (the energy gap $E_+(p = -k_R) - E_-(p = -k_R) = \hbar\Omega$). By the variable Raman pulse length of Raman beam 2, the observed oscillation period of $420 \mu\text{s}$ corresponds to the resonant Raman Rabi frequency $\hbar\Omega = 2.35E_R$.

We adiabatically load the BEC initially in $|\uparrow, 0\rangle$ into the Raman-dressed states of the low E_- or high energy E_+ , simply by ramping the homogeneous bias magnetic field with the different pathes. Here, when the atoms are Raman resonant (at 10.4 MHz with $\delta = 0$) between $|\uparrow\rangle$ and $|\downarrow\rangle$, the detuning between $|\downarrow\rangle$ and $|F = 2, m_F = 0\rangle$ is about $-30E_R$, we may regard it as the two-level system. At last, the Raman dressed states may be characterized by the time-of-flight (TOF). When the Raman beams and the homogeneous bias magnetic field are turned off abruptly, the atoms are projected onto its individual spin and momentum components. The atoms then expand in a magnetic field gradient for 28 ms during TOF along \hat{y} , and the two spin states are separated spatially due to the Stern-Gerlach effect. Imaging the atoms after a 30 ms TOF gives the momentum and spin composition of the dressed state. Now we discuss three cases of loading the BEC into the Raman-dressed states by ramping the homogeneous bias magnetic field with three different paths.

Case 1: We prepare the BEC initially in $|\uparrow, 0\rangle$ locating in the low energy branch E_- with the far positive detuning $\hbar\delta \gg E_R$ by setting the homogeneous bias magnetic field at the value of $B \ll B_0$, as shown in Fig. 2(a) and (b). Here, B_0 corresponds to the $\delta = 0$. Then we ramp the homogeneous bias magnetic field slowly in a time 150 ms to the value with $\hbar\delta = 2E_R$ and hold on in a variable time t_h . Since $\Omega < 4E_R$ in the experiment,

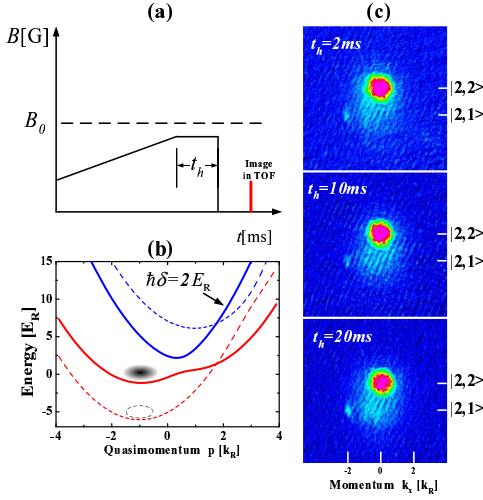


FIG. 2: (Color online). (a) The time sequence of the homogeneous bias magnetic field for loading the atoms into the low-energy Raman-dressed state. The horizontal dashed line indicates B_0 , which corresponds to $\delta = 0$. (b) Energy-quasimomentum dispersion for $\hbar\delta = 2E_R$ (thick solid curves) and $\hbar\delta \gg E_R$ (thin dashed curves) at Raman coupling strength $\hbar\Omega = 2.35E_R$. The quasimomentum of BEC keeps in the low-energy dressed state with $p_{min} < 0$ for $B < B_0$. (c) Images (1.17 mm by 1.17 mm) of the Raman-dressed state for $\hbar\delta = 2E_R$ with variable hold times t_h after a 30 ms TOF. The two spin and momentum components, $|\uparrow, k_x = p_{min} + k_R\rangle$ and $|\downarrow, k_x = p_{min} - k_R\rangle$ [26], are separated along \hat{y} (a Stern-Gerlach field is applied along \hat{y} before the image).

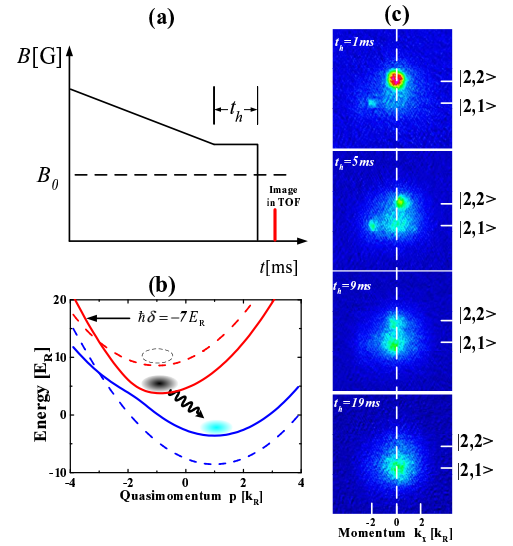


FIG. 4: (Color online). (a) The time sequence for loading the atoms into the high-energy Raman-dressed state. (b) Energy-quasimomentum dispersion for $\hbar\delta = -7E_R$ (thick solid curves) and $\hbar\delta \ll -7E_R$ (thin dashed curves). The atoms start in high-energy Raman-dressed state and ultimately decay into the low-energy Raman-dressed state. (c) Images of the Raman-dressed state for $\hbar\delta = -7E_R$ with variable hold times t_h after a 30 ms TOF.

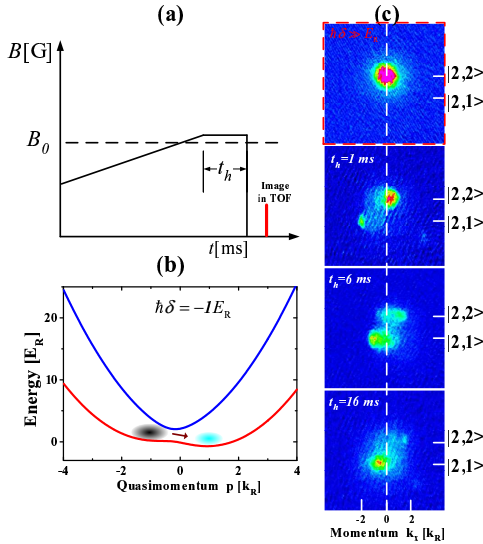


FIG. 3: (Color online). (a) The time sequence for loading the atoms into the low-energy Raman-dressed state. (b) Energy-quasimomentum dispersion for $\hbar\delta = -E_R$ (thick solid curves). The dressed atoms locating at high-energy well of the double wells are unstable and will transit to the low-energy well. (c) Images of the Raman-dressed state for $\hbar\delta = -E_R$ with variable hold times t_h after a 30 ms TOF.

the low energy $E_-(p)$ presents the double wells in quasimomentum space. When $\hbar\delta = 2E_R$, the double wells become asymmetry and the low-energy well locates at $p_{min} = -0.925k_R$. Thus the atoms are loaded to low-energy dressed state adiabatically and locate low-energy well of the double wells at $p_{min} = -0.925k_R$. Figure 2(c) shows spin-resolved TOF images of adiabatically loaded the dressed state with the different holding times. These images demonstrate that the atoms are loaded to low-energy dressed state adiabatically at the low-energy well of the double wells, which are very stable with the long-life time.

Case 2: The initial condition is same as the case 1. The difference is that the homogeneous bias magnetic field is ramped to the value with $\hbar\delta = -E_R$ ($B > B_0$) as shown in Fig. 3(a). The low-energy well of the asymmetry double wells is changed into $p_{min} = 0.889k_R$. The atoms still are loaded to low-energy dressed state adiabatically, however locate at high-energy well (no p_{min}) of the double wells as shown Fig. 3(b). The dressed atoms locating at high-energy well of the double wells are unstable and will transit to the low-energy well. Images in Fig. 3(c) show this transition process. After holding time of 20 ms, the dressed atoms populate the low-energy well of the double wells.

Case 3: We prepare the BEC initially in $|\uparrow, 0\rangle$ locating in the high energy branch E_+ with the far negative detuning $\hbar\delta \ll -E_R$ by setting the homogeneous

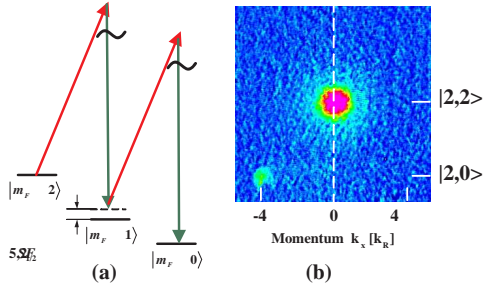


FIG. 5: (Color online). (a) The scheme for generating four-photon Raman process. (b) Images of the four-photon Raman-dressed state after a 30 *ms* TOF. The two spin and momentum components, $|\uparrow, k_x = p_{min} + 2k_R\rangle$ and $|\downarrow, k_x = p_{min} - 2k_R\rangle$, are separated along \hat{y} .

bias magnetic field at the value of $B > B_0$, as shown in Fig. 4(a) and (b). The homogeneous bias magnetic field is decreased to the value with $\hbar\delta = -7E_R$ and the atoms are loaded to high-energy dressed state adiabatically. The high energy branch $E_+(p)$ consists of single well in quasi-momentum space, thus the dressed atoms locate at $p_{min} = -0.84k_R$. The dressed atoms in high quasibands are energetically allowed, however, collisional decay will present near Raman resonance except the lowest-energy dressed state [10]. The decay for variable hold times ranging from 1 *ms* to 19 *ms* is observed as shown in Fig. 4(c). The dressed atoms in high quasibands decay into the low-energy band accompanying the heating, which is a completely different process compared with that of case 2.

Moreover, the four-photon Raman process with $4\hbar k_R$ momentum is observed, which may be used to generate the light-induce vector gauge potential consisting of the high momentum components. The similar method has been done [31] that the cold atoms were coherently transferred from one dressed state to another one by a multi-photon process, which changed the atom momentum by several photon recoils. When the atoms are Raman red detuning with $\delta = -15E_R$ between $|\uparrow\rangle$ and $|\downarrow\rangle$, so the blue detuning between $|\downarrow\rangle$ and $|F=2, m_F=0\rangle$ is $+15E_R$, the condition for the four-photon resonant Raman process ($2\nu_R = \omega_Z^{(2,2) \leftrightarrow (2,0)}$) is satisfied as shown in Fig. 5(a). The nonzero two-photon detuning $\delta = \pm 15E_R$ is used to suppress resonant two-photon Raman process. Therefore, the spin state $|F=2, m_F=1\rangle$ has negligible contribution in case of the large detuning. We may regard it as the two-level system consisting of $|F=2, m_F=2\rangle$ and $|F=2, m_F=0\rangle = |\tilde{\downarrow}\rangle$. When ramping the homogeneous bias magnetic field slowly from low field to the four-photon Raman resonance, the atoms are loaded to low-energy dressed state. The two spin and momentum components ($|\uparrow, k_x = p_{min} + 2k_R\rangle$ and $|\tilde{\downarrow}, k_x = p_{min} - 2k_R\rangle$) for the dressed state are observed as shown in Fig. 5(b).

It will be useful to produce the large size of double wells in quasi-momentum space.

In conclusion, we have demonstrated an effective vector gauge potential for ^{87}Rb BEC in the $F=2$ hyperfine ground state, which was generated by using two crossed 1064 *nm* optical dipole trap lasers to be the Raman beams. The effective vector gauge potential still can be generated (in the atomic long lifetime due to photon scattering in the optical dipole trap) by the very far-detuning (larger than the excited-state fine structure splitting) between the single-photon resonance and the excited state transition, since rubidium has 15 *nm* the excited-state fine structure splitting [10, 26]. The experimental scheme can be applied to produce the synthetic magnetic or electric field by means of a spatial or time dependence of the effective vector potential.

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SUPPLEMENTARY MATERIAL

Two – level model: We describe in detail theoretical model of two-level system for generating light- induce vector gauge potential. Two Raman beams have frequencies ω_R and $\omega_R + \nu_R$, and a bias field B along \hat{x} produces a Zeeman shift $\hbar\omega_Z = g\mu_B B$. Since the momentum transfer induced by the Raman beams is along \hat{x} , the Hamiltonian is written as $H = H_R(k_x) + [\hbar^2(k_y^2 + k_z^2)/2m + V(\bar{r})]$, where $H_R(k_x)$ is the Hamiltonian for the Raman coupling, the Zeeman energies and the motion along \hat{x} . $V(\bar{r})$ is the state-independent trapping potential arising from the scalar light trap of the Raman beams and m is the atomic mass. Under the rotating-wave approximation in the frame rotating at ν_R , the Hamiltonian $H_R(k_x)$ is written in the bare atomic state basis of $\{|\uparrow, k_x = p + k_R\rangle, |\downarrow, k_x = p - k_R\rangle\}$

$$H_R(k_x) = \hbar \begin{pmatrix} \frac{\hbar}{2m}(p + k_R)^2 - \delta/2 & \Omega/2 \\ \Omega/2 & \frac{\hbar}{2m}(p - k_R)^2 + \delta/2 \end{pmatrix}. \quad (1)$$

Here $\delta = \nu_R - \omega_Z$ is the detuning from Raman resonance, Ω is the resonant Raman Rabi frequency, p denotes quasi-momentum. $k_R = k_r \sin(\theta/2)$, $k_r = 2\pi/\lambda$ is the single-photon recoil momentum, λ is the wavelength of the Raman beam, and $\theta = 90^\circ$ is the intersecting angle of two Raman beams. $\hbar k_R$ and $E_R = (\hbar k_R)^2/2m = h \times 1.013$ kHz are the units of momentum and energy, respectively. $H_R(k_x)$ are diagonalized to get two energy eigenvalues $E_\pm(p) = \hbar[\hbar(p^2 + k_R^2)/2m \pm \sqrt{(4\hbar p k_R/2m - \delta)^2 + \Omega^2}/2]$, which give the effective dispersion relations of the dressed states. The two dressed eigenstates are expressed by

$$\begin{aligned} |\uparrow', p\rangle &= c_1 |\uparrow, k_x = p + k_R\rangle + c_2 |\downarrow, k_x = p - k_R\rangle \\ |\downarrow', p\rangle &= c_3 |\uparrow, k_x = p + k_R\rangle + c_4 |\downarrow, k_x = p - k_R\rangle. \end{aligned} \quad (2)$$

Here, $c_1 = 1/\sqrt{a^2 + 1}$, $c_2 = a/\sqrt{a^2 + 1}$, and $a = -(4\hbar p k_R/2m - \delta - \sqrt{(4\hbar p k_R/2m - \delta)^2 + \Omega^2})/\Omega$. $c_3 = 1/\sqrt{b^2 + 1}$, $c_4 = b/\sqrt{b^2 + 1}$, and $b = -(4\hbar p k_R/2m - \delta + \sqrt{(4\hbar p k_R/2m - \delta)^2 + \Omega^2})/\Omega$. $|\uparrow', p\rangle$ is the high-energy dressed state for $E_+(p)$ and $|\downarrow', p\rangle$ is the low-energy dressed state for $E_-(p)$. Since the high and low energies E_\pm of the dressed states depend on the experimental parameters Ω and δ , the positions of energy minima (p_{min}) are thus experimentally tunable. For $\Omega < 4E_R$ and small δ , the lowest energy $E_-(p)$ consists of double

wells in quasi-momentum space. As $\Omega > 4E_R$, the double wells merge into a single well.

Raman coupling strength and scattering rate: The general expressions for the optical dipole potential and the scattering rate are given by [1]

$$\begin{aligned} U_{dip} &\simeq \frac{\hbar\Gamma^2}{8\Delta} \frac{I}{I_s}, \\ \gamma_P &\simeq \frac{\Gamma^3}{8\Delta^2} \frac{I}{I_s}, \end{aligned} \quad (3)$$

where Γ is the spontaneous decay rate of the excited level, Δ is single photon detuning, $I_s = 2\pi^2\hbar c\Gamma/3\lambda^3$ is the saturation intensity (λ is optical wavelength and c is the speed of light). If the single photon detuning is larger ($\Delta \gg \nu_{FS}$) than the excited state fine structure intervals for alkali-metal, the Raman coupling strength is

$$\Omega \simeq \frac{\Gamma^2}{8\Delta} \frac{\nu_{FS}}{\Delta} \frac{\sqrt{I_1 I_2}}{I_s}, \quad (4)$$

where ν_{FS} is the excited-state fine-structure splitting, I_1 and I_2 are the intensities of two Raman beams. The dipole potential scales as I/Δ , whereas the scattering rate scales as I/Δ^2 . Therefore, optical dipole traps usually use large detunings and high intensities to keep the scattering rate as low as possible at a certain potential depth. However, the rate of the Raman coupling strength and the scattering rate is close to a constant $\propto \nu_{FS}/\Gamma$ when the single photon detuning is larger than the excited state fine structure. Therefore it is useless to increase the detuning Δ to improve the ratio between the Raman coupling strength and the scattering rate [2]. However, the moderate strength of the Raman coupling still can be obtained during the atomic lifetime due to photon scattering in the optical dipole trap for the larger single photon detuning in the paper, since rubidium has 15 nm the excited-state fine structure splitting.

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